

C2M1000170D

C2M1000170D Information





Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



C2M1000170D Specifications

Manufacturer Part Number	C2M1000170D
Manufacturer	Cree/Wolfspeed
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	ТО-247-3
Series	Z-FET?
FET Type	N-Channel
Technology	SiCFET (Silicon Carbide)
Drain to Source Voltage (Vdss)	1700V
Current - Continuous Drain (Id) @ 25°C	4.9A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	20V
Vgs(th) (Max) @ Id	2.4V @ 100µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 20V
Input Capacitance (Ciss) (Max) @ Vds	191pF @ 1000V
Vgs (Max)	+25V, -10V
FET Feature	-
Power Dissipation (Max)	69W (Tc)
Rds On (Max) @ Id, Vgs	1.1 Ohm @ 2A, 20V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	ТО-247-3
Package / Case	ТО-247-3
	Report errors?

E-mail: salesdept@heisener.com

C2M1000170D Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE UARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

C2M1000170D Payment Methods



C2M1000170D Shipping Methods



If you have any question about C2M1000170D, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com